

# BCP56-16

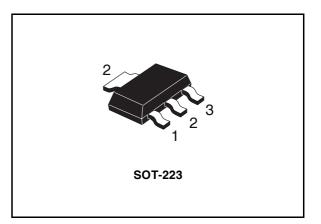
### Low power NPN Transistor

### **General features**

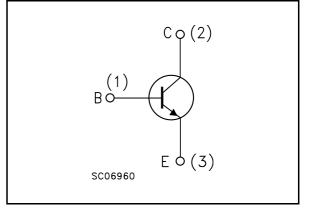
- Silicon epitaxial planar NPN medium voltage transistor
- SOT-223 plastic package for surface mounting circuits
- Available in tape & reel packing
- In compliance with the 2002/93/EC European Directive
- The PNP complementary type is BCP53-16

### Applications

- Medium voltage load switch transistor
- Output stage for audio amplifiers circuits
- Automotive post-voltage regulation



### Internal schematic diagram



### **Order codes**

| Part Number | Marking             | Package | Packing     |
|-------------|---------------------|---------|-------------|
| BCP56-16    | P56-16 BCP5616 SOT- |         | Tape & reel |

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### 1

# **Electrical ratings**

| Table 1.Absolute maximum rating |
|---------------------------------|
|---------------------------------|

| Symbol           | Parameter                                      | Value      | Unit |
|------------------|--|------------|------|
| V <sub>CBO</sub> | Collector-base voltage (I <sub>E</sub> = 0)    | 100        | V    |
| V <sub>CEO</sub> | Collector-emitter voltage (I <sub>B</sub> = 0) | 80         | V    |
| V <sub>EBO</sub> | Emitter-base voltage (I <sub>C</sub> = 0)      | 5          | V    |
| Ι <sub>C</sub>   | Collector current                              | 1          | А    |
| I <sub>СМ</sub>  | Collector peak current (t <sub>P</sub> < 5ms)  | 1.5        | А    |
| Ι <sub>Β</sub>   | Base current                                   | 0.1        | А    |
| I <sub>BM</sub>  | Base peak current (t <sub>P</sub> < 5ms)       | 0.2        | А    |
| P <sub>tot</sub> | Total dissipation at $T_{amb} = 25^{\circ}C$   | 1.6        | W    |
| T <sub>stg</sub> | Storage temperature                            | -65 to 150 | °C   |
| TJ               | Max. operating junction temperature            | 150        | °C   |

#### Table 2. Thermal data

| Symbol               | Parameter  | Value | Unit |
|----------------------|--|-------|------|
| R <sub>thj-amb</sub> | Thermal resistance junction-ambient <sup>(1)</sup> max | 78    | °C/W |

1. Device mounted on PCB area of 1 cm<sup>2</sup>.

# 2 Electrical characteristics

( $T_{case} = 25^{\circ}C$  unless otherwise specified)

| Symbol                              | Parameter   | Test Conditions   | Min.            | Тур. | Max.      | Unit     |
|-------------------------------------|---|---|-----------------|------|-----------|----------|
| I <sub>CBO</sub>                    | Collector cut-off current<br>(I <sub>E</sub> =0)                        | V <sub>CB</sub> = 30V<br>V <sub>CB</sub> = 30V; T <sub>j</sub> = 125°C  |                 |      | 100<br>10 | nA<br>μA |
| V <sub>(BR)CEO</sub> <sup>(2)</sup> | Collector-emitter<br>breakdown voltage $I_{C} = 20$ mA<br>$(I_{B} = 0)$ |   | 80              |      |           | V        |
| V <sub>(BR)CBO</sub>                | Collector-base<br>breakdown voltage<br>(I <sub>E</sub> =0)              | I <sub>C</sub> = 100μΑ  | 100             |      |           | V        |
| V <sub>(BR)EBO</sub>                | Emitter-base breakdown<br>voltage (I <sub>C</sub> =0)                   | I <sub>E</sub> = 10μA   | 5               |      |           | V        |
| V <sub>CE(sat)</sub> <sup>(2)</sup> | Collector-emitter saturation voltage                                    | I <sub>C</sub> = 500mA I <sub>B</sub> = 50mA  |                 |      | 0.5       | V        |
| V <sub>BE(on)</sub> <sup>(2)</sup>  | Base-emitter on voltage   | $I_{C} = 500 \text{mA}$ $V_{CE} = 2 \text{V}$   |                 |      | 1         | V        |
| h <sub>FE</sub> <sup>(2)</sup>      | DC current gain   | $\label{eq:lc} \begin{array}{ll} I_{C} = 5mA & V_{CE} = 2V \\ I_{C} = 150mA & V_{CE} = 2V \\ I_{C} = 500mA & V_{CE} = 2V \end{array}$ | 40<br>100<br>25 |      | 250       |          |

 Table 3.
 Electrical characteristics

Note (2) Pulsed duration = 300  $\mu$ s, duty cycle  $\leq$ 1.5%



## 2.1 Electrical characteristics (curves)

#### Figure 1. DC current gain

# Figure 2. Collector-emitter saturation voltage

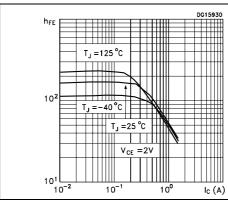
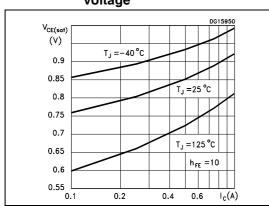


Figure 3. Base-emitter saturation voltage



 $\begin{array}{c} & & & & & & \\ V_{CE(sof)} & & & & & \\ (V) & & & & \\ & & & \\ (V) & & & & \\ & & & \\ T_{J} = 25 \ ^{\circ}C & & \\ & & & \\ & & & \\ T_{J} = -40 \ ^{\circ}C & & \\ & & & \\ & & & \\ 0.01 & & \\ 0.1 & & 0.2 & & 0.4 & & 0.6 \quad I_{c}(A) \end{array}$ 



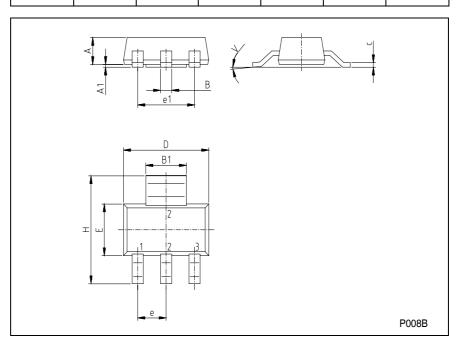
## 3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com



| SOI-223 MECHANICAL DATA |      |      |      |       |       |                 |  |
|-------------------------|------|------|------|-------|-------|-----------------|--|
| DIM.                    |      | mm   |      |       | inch  |                 |  |
|                         | MIN. | TYP. | MAX. | MIN.  | TYP.  | MAX.            |  |
| А                       |      |      | 1.80 |       |       | 0.071           |  |
| В                       | 0.60 | 0.70 | 0.80 | 0.024 | 0.027 | 0.031           |  |
| B1                      | 2.90 | 3.00 | 3.10 | 0.114 | 0.118 | 0.122           |  |
| С                       | 0.24 | 0.26 | 0.32 | 0.009 | 0.010 | 0.013           |  |
| D                       | 6.30 | 6.50 | 6.70 | 0.248 | 0.256 | 0.264           |  |
| е                       |      | 2.30 |      |       | 0.090 |                 |  |
| e1                      |      | 4.60 |      |       | 0.181 |                 |  |
| Е                       | 3.30 | 3.50 | 3.70 | 0.130 | 0.138 | 0.146           |  |
| Н                       | 6.70 | 7.00 | 7.30 | 0.264 | 0.276 | 0.287           |  |
| ٧                       |      |      | 10°  |       |       | 10 <sup>0</sup> |  |
| A1                      |      | 0.02 |      |       |       |                 |  |





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# 4 Revision history

| Date        | Revision | Changes                                |  |
|-------------|----------|--|--|
| 02-Sep-2004 | 1        | Initial release.                       |  |
| 26-May-2006 | 2        | New template                           |  |
| 14-Jun-2006 | 3        | Three curves has been added on page 5. |  |



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